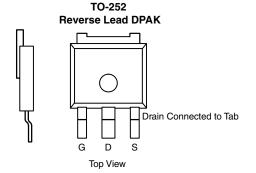


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Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET

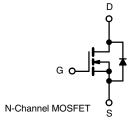
| PRODUCT SUMMARY | | | | |
|---|--------|--|--|--|
| V _{DS} (V) | 40 | | | |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$ | 0.0038 | | | |
| I _D (A) | 50 | | | |
| Configuration | Single | | | |



FEATURES

- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- AEC-Q101 Qualified^d
- 100 % R_g and UIS Tested
- Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912





| ORDERING INFORMATION | |
|---------------------------------|--------------------------|
| Package | TO-252 Reverse Lead DPAK |
| Lead (Pb)-free and Halogen-free | SQR50N04-3m8-GE3 |

| ABSOLUTE MAXIMUM RATING | i5 (1 _C = 25 °C, unles | s otnerwise noted | a) | |
|---|--|-----------------------------------|---------------|-----|
| PARAMETER | SYMBOL | LIMIT | UNIT | |
| Drain-Source Voltage | | V_{DS} | 40 | V |
| Gate-Source Voltage | | V_{GS} | ± 20 | V |
| Continuous Drain Current ^a | T _C = 25 °C | - I _D | 50 | |
| | T _C = 125 °C | | 50 | |
| Continuous Source Current (Diode Conduction) ^a | | I _S | 50 | А |
| Pulsed Drain Current ^b | | I _{DM} | 200 | |
| Single Pulse Avalanche Current | L = 0.1 mH | I _{AS} | 62 | |
| Single Pulse Avalanche Energy | L = 0.1 MH | E _{AS} | 192 | mJ |
| Maximum Power Dissipation ^b | T _C = 25 °C | | 136 | 10/ |
| | T _C = 125 °C | P_D | 45 | W |
| Operating Junction and Storage Temperatu | re Range | T _J , T _{stg} | - 55 to + 175 | °C |

| THERMAL RESISTANCE RATINGS | | | | | |
|----------------------------|------------------------|-------------------|-------|------|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | |
| Junction-to-Ambient F | PCB Mount ^c | R _{thJA} | 50 | °C/W | |
| Junction-to-Case (Drain) | | R_{thJC} | 1.1 | C/VV | |

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.



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| PARAMETER | SYMBOL | TES | MIN. | TYP. | MAX. | UNIT | |
|---|--------------------------|--|---|------|--------|--------|----|
| Static | | | | | • | ı | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$ | | 40 | | - | V |
| Gate-Source Threshold Voltage | V _{GS(th)} | V _{DS} = | $V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$ | | 3.0 | 3.5 | V |
| Gate-Source Leakage | I _{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$ | | - | - | ± 100 | nA |
| | | V _{GS} = 0 V | V _{DS} = 40 V | - | - | 1 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{GS} = 0 V | V _{DS} = 40 V, T _J = 125 °C | - | - | 50 | μΑ |
| | | V _{GS} = 0 V | V _{DS} = 40 V, T _J = 175 °C | - | - | 150 | |
| On-State Drain Current ^a | I _{D(on)} | V _{GS} = 10 V | $V_{DS} \ge 5 V$ | 50 | - | - | Α |
| | | V _{GS} = 10 V | I _D = 20 A | - | 0.0030 | 0.0038 | Ω |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = 10 V | I _D = 20 A, T _J = 125 °C | - | - | 0.0064 | |
| | | V _{GS} = 10 V | I _D = 20 A, T _J = 175 °C | - | - | 0.0076 | |
| Forward Transconductance ^b | 9 _{fs} | V _{DS} | V _{DS} = 15 V, I _D = 15 A | | 120 | - | S |
| Dynamic ^b | | | | | | | |
| Input Capacitance | C _{iss} | | | - | 5360 | 6700 | |
| Output Capacitance | C _{oss} | $V_{GS} = 0 V$ | V _{GS} = 0 V V _{DS} = 25 V, f = 1 MHz | | 500 | 627 | рF |
| Reverse Transfer Capacitance | C _{rss} | | | - | 250 | 310 | |
| Total Gate Charge ^c | Qg | | | - | 70 | 105 | |
| Gate-Source Charge ^c | Q_{gs} | V _{GS} = 10 V | $V_{DS} = 20 \text{ V}, I_D = 50 \text{ A}$ | - | 16 | - | nC |
| Gate-Drain Charge ^c | Q _{gd} |] | | | 13 | - | |
| Gate Resistance | R _g | | f = 1 MHz | | 1.9 | 2.9 | Ω |
| Turn-On Delay Time ^c | t _{d(on)} | $V_{DD} = 20 \text{ V}, \text{ R}_L = 0.4 \Omega$ $I_D \cong 50 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_g = 1 \Omega$ | | - | 11 | 16 | |
| Rise Time ^c | t _r | | | - | 5 | 8 | ns |
| Turn-Off Delay Time ^c | t _{d(off)} | | | - | 34 | 51 | |
| Fall Time ^c | t _f | | | - | 9 | 14 | |
| Source-Drain Diode Ratings and Chara | acteristics ^b | | | | | | |
| Pulsed Current ^a | I _{SM} | | | - | - | 200 | Α |
| Forward Voltage | V_{SD} | I _F = 30 A, V _{GS} = 0 V | | _ | 0.9 | 1.5 | V |

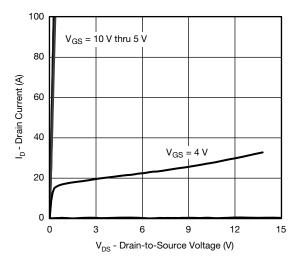
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

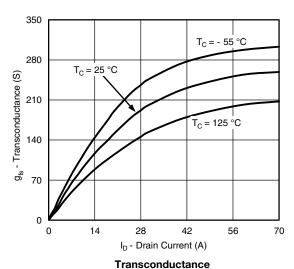
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

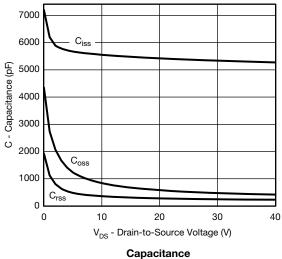


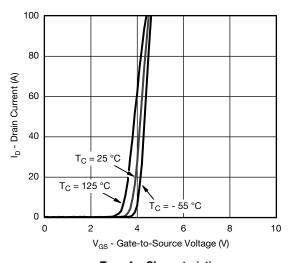
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



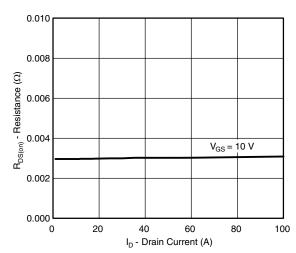
Output Characteristics



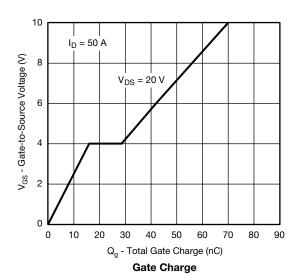




Transfer Characteristics

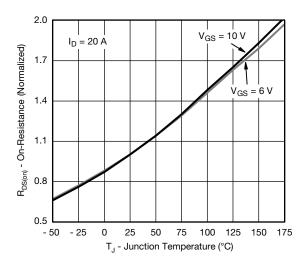


On-Resistance vs. Drain Current

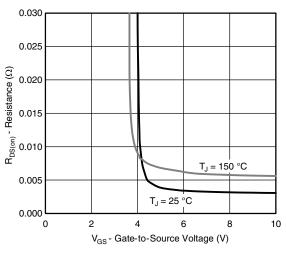




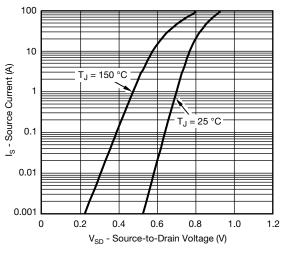
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



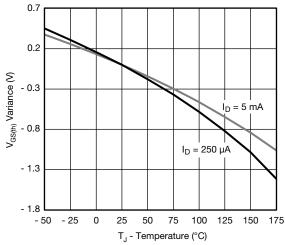
On-Resistance vs. Junction Temperature



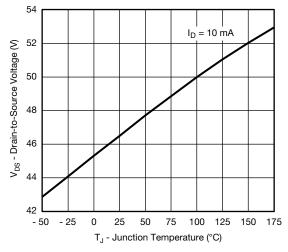
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



Threshold Voltage

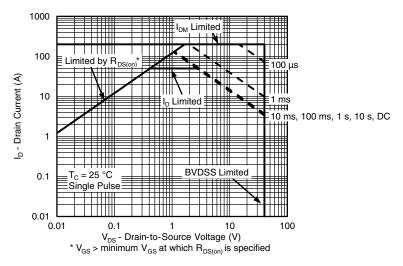


Drain Source Breakdown vs. Junction Temperature

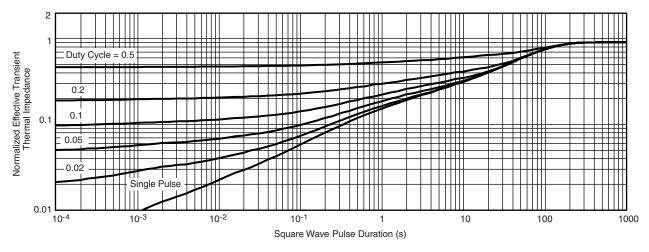
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THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



Safe Operating Area

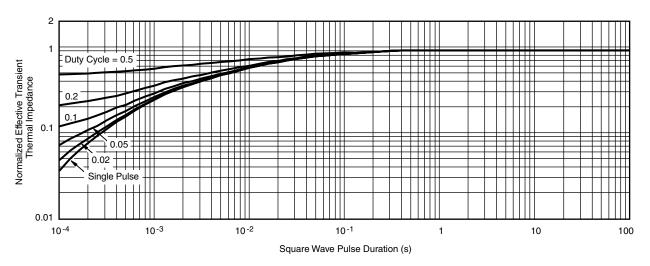


Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62783.

Vishay Siliconix

DPAK / TO-252 and Reverse DPAK

Ordering codes for the SQ rugged series power MOSFETs in the DPAK / TO-252 and Reverse DPAK packages:

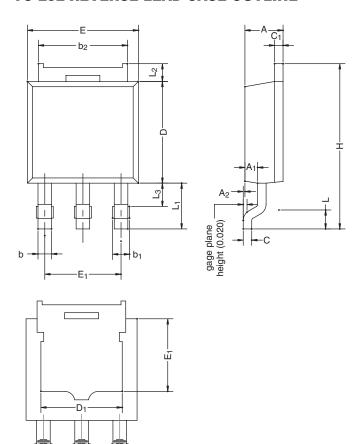
| DATASHEET PART NUMBER | OLD ORDERING CODE a | NEW ORDERING CODE |
|-----------------------|---------------------|--------------------|
| SQD07N25-350H | SQD07N25-350H-GE3 | SQD07N25-350H_GE3 |
| SQD100N02-3m5L | · | SQD100N02-3m5L_GE3 |
| SQD100N03-3m2L | SQD100N03-3M2L-GE3 | SQD100N03-3M2L_GE3 |
| SQD100N03-3m4 | SQD100N03-3M4-GE3 | SQD100N03-3M4_GE3 |
| SQD100N04-3m6 | SQD100N04-3M6-GE3 | SQD100N04-3M6_GE3 |
| SQD100N04-3m6L | SQD100N04-3M6L-GE3 | SQD100N04-3M6L_GE3 |
| SQD10N30-330H | SQD10N30-330H-GE3 | SQD10N30-330H_GE3 |
| SQD15N06-42L | SQD15N06-42L-GE3 | SQD15N06-42L_GE3 |
| SQD19P06-60L | SQD19P06-60L-GE3 | SQD19P06-60L_GE3 |
| SQD23N06-31L | SQD23N06-31L-GE3 | SQD23N06-31L_GE3 |
| SQD25N06-22L | SQD25N06-22L-GE3 | SQD25N06-22L_GE3 |
| SQD25N15-52 | SQD25N15-52-GE3 | SQD25N15-52_GE3 |
| SQD30N05-20L | SQD30N05-20L-GE3 | SQD30N05-20L_GE3 |
| SQD40N06-14L | SQD40N06-14L-GE3 | SQD40N06-14L_GE3 |
| SQD40N10-25 | SQD40N10-25-GE3 | SQD40N10-25_GE3 |
| SQD40P10-40L | SQD40P10-40L-GE3 | SQD40P10-40L_GE3 |
| SQD45P03-12 | SQD45P03-12-GE3 | SQD45P03-12_GE3 |
| SQD50N04-5m6 | SQD50N04-5M6-GE3 | SQD50N04-5M6_GE3 |
| SQD50N04-5m6L | - | SQD50N04-5m6L_GE3 |
| SQD50N05-11L | SQD50N05-11L-GE3 | SQD50N05-11L_GE3 |
| SQD50N06-09L | SQD50N06-09L-GE3 | SQD50N06-09L_GE3 |
| SQD50N10-8m9L | SQD50N10-8M9L-GE3 | SQD50N10-8M9L_GE3 |
| SQD50P03-07 | SQD50P03-07-GE3 | SQD50P03-07_GE3 |
| SQD50P04-13L | SQD50P04-13L-GE3 | SQD50P04-13L_GE3 |
| SQD50P04-09L | SQD50P04-09L-GE3 | SQD50P04-09L_GE3 |
| SQD50P06-15L | SQD50P06-15L-GE3 | SQD50P06-15L_GE3 |
| SQD50P08-25L | SQD50P08-25L-GE3 | SQD50P08-25L_GE3 |
| SQD50P08-28 | SQD50P08-28-GE3 | SQD50P08-28_GE3 |
| SQD90P04-9m4L | SQD90P04-9M4L-GE3 | SQD90P04-9M4L_GE3 |
| SQD97N06-6m3L | SQD97N06-6M3L-GE3 | SQD97N06-6M3L_GE3 |
| SQR40N10-25 | SQR40N10-25-GE3 | SQR40N10-25_GE3 |
| SQR50N04-3m8 | SQR50N04-3M8-GE3 | SQR50N04-3M8 GE3 |

Note

a. Old ordering code is obsolete and no longer valid for new orders



TO-252 REVERSE LEAD CASE OUTLINE



| | MILLIN | METERS | INCHES | | | |
|--------------------------------|-------------------------|--------|-----------|-----------|--|--|
| DIM. | MIN. | MAX. | MIN. | MAX. | | |
| Α | 2.23 | 2.33 | 0.088 | 0.092 | | |
| A ₁ | 0.64 | 0.89 | 0.025 | 0.035 | | |
| A ₂ | 0.03 | 0.23 | 0.001 | 0.009 | | |
| b | 0.71 | 0.88 | 0.028 | 0.035 | | |
| b ₁ | 0.76 | 1.14 | 0.030 | 0.045 | | |
| b ₂ | 5.23 | 5.44 | 0.206 | 0.214 | | |
| С | 0.46 | 0.58 | 0.018 | 0.023 | | |
| C ₁ | 0.46 | 0.58 | 0.018 | 0.023 | | |
| D | 5.97 | 6.22 | 0.235 | 0.245 | | |
| D ₁ | 4.49 | 5.00 | 0.177 | 0.197 | | |
| Е | 6.48 | 6.73 | 0.255 | 0.265 | | |
| E ₁ | 4.32 | - | 0.170 | - | | |
| е | e 2.28 BSC 0.090 BSC | | | | | |
| e ₁ | e ₁ 4.57 BSC | | | 0.180 BSC | | |
| Н | 9.65 | 10.41 | 0.380 | 0.410 | | |
| L | 1.40 | 1.78 | 0.055 | 0.070 | | |
| L ₁ | 2.74 BSC | | 0.108 BSC | | | |
| L ₂ | 0.89 | 1.27 | 0.035 | 0.050 | | |
| L ₃ | 1.15 | 1.52 | 0.040 | 0.060 | | |
| ECN: T-08706-Rev. B, 29-Sep-08 | | | | | | |

DWG: 5894

Note

Dimension L₃ for reference only.



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Revision: 02-Oct-12 Document Number: 91000

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IPS70R2K0CEAKMA1 BUK954R8-60E DMN3404LQ-7 NTE6400 SQJ402EP-T1-GE3 2SK2614(TE16L1,Q) 2N7002KW-FAI

DMN1017UCP3-7 EFC2J004NUZTDG ECH8691-TL-W FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE221 NTE2384

NTE2903 NTE2941 NTE2945 NTE2946 NTE2960 NTE2967 NTE2969 NTE2976 NTE455 NTE6400A NTE2910 NTE2916 NTE2956

NTE2911 TK10A80W,S4X(S SSM6P69NU,LF DMP22D4UFO-7B